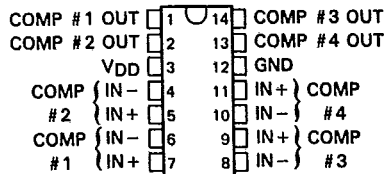


TLC354M, TLC354I, TLC354C
LinCMOS™ QUADRUPLE DIFFERENTIAL COMPARATORS

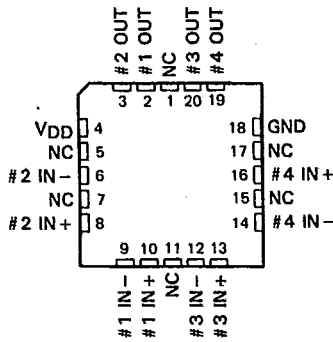
D2901, SEPTEMBER 1985—REVISED FEBRUARY 1989

- Single- or Dual-Supply Operation
- Wide Range of Supply Voltages . . . 1.4 V to 18 V
- Very Low Supply Current Drain
 300 μ A Typ at 5 V
 130 μ A Typ at 1.4 V
- Built-In ESD Protection
- High Input Impedance . . . 10¹² Typ
- Extremely Low Input Bias Current 5 pA Typ
- Ultrastable Low Input Offset Voltage
- Input Offset Voltage Change at Worst-Case Input Conditions Typically 0.23 μ V/Month, Including the First 30 Days
- Common-Mode Input Voltage Range Includes Ground
- Outputs Compatible with TTL, MOS, and CMOS
- Pin-Compatible with LM339

TLC354M . . . J PACKAGE
 TLC354I, TLC354C . . . D OR N PACKAGE **T-73-53**

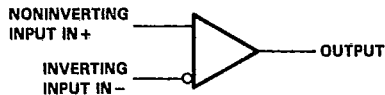


TLC354M . . . FK PACKAGE
 (TOP VIEW)



NC—No internal connection

symbol (each comparator)



description

This device is fabricated using LinCMOS™ technology and consists of four independent voltage comparators; each designed to operate from a single power supply. Operation from dual supplies is also possible so long as the difference between the two supplies is 1.4 V to 18 V. Each device features extremely high input impedance (typically greater than 10¹² Ω), which allows direct interface to high-impedance sources. The outputs are n-channel open-drain configurations and can be connected to achieve positive-logic wired-AND relationships. The capability of the TLC354 to operate from a 1.4-V supply makes this device ideal for low-voltage battery applications.

The TLC354 has internal electrostatic discharge (ESD) protection circuits and has been classified with a 2000-V ESD rating tested under MIL-STD-883C, Method 3015. However, care should be exercised in handling this device as exposure to ESD may result in degradation of the device parametric performance.

The TLC354M is characterized for operation over the full military temperature range of -55°C to 125°C. The TLC354I is characterized for operation over the industrial temperature range of -40°C to 85°C. The TLC354C is characterized for operation from 0°C to 70°C.

LinCMOS is a trademark of Texas Instruments Incorporated.

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655012 • DALLAS, TEXAS 75265

Copyright © 1985, Texas Instruments Incorporated

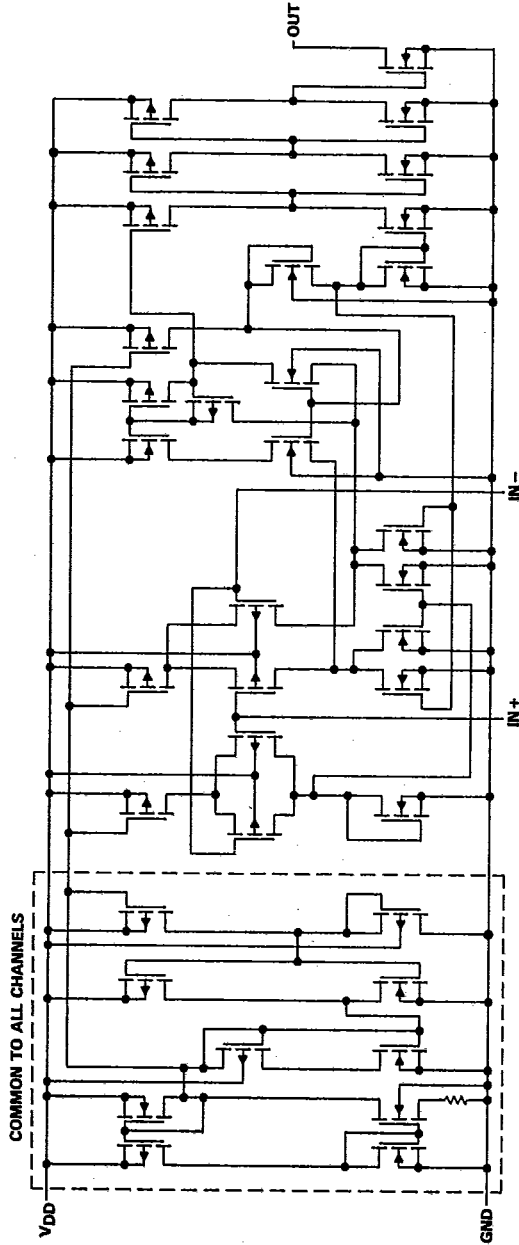
3-111

3
Voltage Comparators

T-73-53

TEXAS INSTR (LIN/INTFC)

equivalent schematic (each comparator)



3

Voltage Comparators

TLC354M, TLC354I, TLC354C
LinCMOS™ QUADRUPLE DIFFERENTIAL COMPARATORS

TEXAS INSTR (LIN/INTFC) T-73-53

AVAILABLE OPTIONS

T _A	V _{IO} MAX AT 25°C	PACKAGE			
		SMALL-OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)
0°C to 70°C	5 mV	TLC354CD	—	TLC354CJ	TLC354CN
-40°C to 85°C	5 mV	TLC354ID	—	TLC354IJ	TLC354IN
-55°C to 125°C	5 mV	—	TLC354MFK	TLC354MJ	—

D packages are available taped and reeled. Add "R" suffix to device type when ordering (e.g., TLC354CDR).

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{DD} (see Note 1)	18 V
Differential input voltage, V _{ID} (see Note 2)	±18 V
Input voltage, V _I	V _{DD}
Input voltage range	-0.3 V to 18 V
Output voltage, V _O	18 V
Input current, I _I	±5 mA
Output current, I _O	20 mA
Duration of output short-circuit to ground (see Note 3)	unlimited
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range: TLC354M	-55°C to 125°C
TLC354I	-40°C to 85°C
TLC354C	0°C to 70°C
Storage temperature range	-65°C to 150°C
Case temperature for 60 seconds: FK package	260°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J package	300°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or N package	260°C

- NOTES: 1. All voltage values except differential voltages are with respect to network ground.
 2. Differential voltages are at the noninverting input terminal with respect to the inverting input terminal.
 3. Short circuits from outputs to V_{DD} can cause excessive heating and eventual device destruction.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING	DERATE	T _A = 70°C	T _A = 85°C	T _A = 125°C
	POWER RATING	FACTOR	ABOVE T _A	POWER RATING	POWER RATING	POWER RATING
D	500 mW	7.6 mW/°C	84°C	500 mW	494 mW	N/A
FK	500 mW	11.0 mW/°C	104°C	500 mW	500 mW	275 mW
J (TLC354M)	500 mW	11.0 mW/°C	104°C	500 mW	500 mW	275 mW
J (TLC354I, TLC354C)	500 mW	N/A	N/A	500 mW	500 mW	N/A
N	500 mW	N/A	N/A	500 mW	500 mW	N/A

Voltage Comparators

T-73-53

Voltage Comparators

recommended operating conditions

	M-SUFFIX			I-SUFFIX			C-SUFFIX			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, VDD	1.4	1.4	16	1.4	1.4	16	1.4	1.4	16	V
Common-mode input voltage, V _{IC}	V _{DD} = 5 V			0	0	3.5	0	0	3.5	V
	V _{DD} = 10 V			0	0	8.5	0	0	8.5	V
Operating free-air temperature, T _A	-55	125	-40	85	0	70	0	70	0	°C

electrical characteristics at specified free-air temperature, VDD = 1.4 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	TLC354M			TLC354I			TLC354C			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO} Input offset voltage	V _{IC} = V _{ICR} min, See Note 4	25°C	2	5	2	2	5	2	2	5	mV
		Full range		10		7		6.5			
I _{IO} Input offset current	MAX T _A	25°C	1		1		1		1		pA
		MAX T _A	5		5		5		5		pA
I _{IB} Input bias current	MAX T _A	25°C	0 to 0.2		0 to 0.2		0 to 0.2		0 to 0.2		nA
		MAX T _A	0.1		0.1		0.1		0.1		nA
V _{ICR} Common-mode input voltage range	V _{ID} = 1 V	25°C	100	200	100	200	100	200	100	200	mV
		Full range	200	200	200	200	200	200	200	200	
I _{OH} High-level output current	V _{OH} = 5 V	25°C	1	1.6	1	1.6	1	1.6	1	1.6	mA
		Full range	130	300	130	300	130	300	130	300	
I _{OL} Low-level output current	V _{OL} = -0.5 V, I _{OL} = 0.6 mA	25°C	1	1.6	1	1.6	1	1.6	1	1.6	mA
		Full range	130	300	130	300	130	300	130	300	
I _{DD} Supply current (four comparators)	V _{DD} = 0.5 V, No load	25°C	0.1	0.2	0.1	0.2	0.1	0.2	0.1	0.2	μA
		Full range	130	400	130	400	130	400	130	400	

†All characteristics are measured with zero common-mode input voltage unless otherwise noted. Full range is -55°C to 125°C for TLC354M, -40°C to 85°C for TLC354I, and 0°C to 70°C for TLC354C. IMPORTANT: See Parameter Measurement Information.

NOTE 4: The offset voltage limits given are the maximum values required to drive the output above 1.25 V or below 150 mV with a 10-kΩ resistor between the output and V_{DD}. They can be verified by applying the limit value to the input and checking for the appropriate output state.

TLC354M, TLC354I, TLC354C
LinCMOS™ QUADRUPLE DIFFERENTIAL COMPARATORS

T-73-53

electrical characteristics at specified free-air temperature, VDD = 5 V (unless otherwise noted)

PARAMETER	TEST CONDITIONS†			TLC354M			TLC354I			TLC354C			UNIT
	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{IO} Input offset voltage	25°C			2	10	10	2	10	10	2	10	10	mV
	Full range			12	12	13	1	1	1	1	1	1	
I _{IO} Input offset current	25°C			1	1	1	1	1	1	1	1	1	pA
	MAX TA			10	10	1	1	1	1	1	1	1	
I _{IB} Input bias current	25°C			5	5	5	5	5	5	5	5	5	pA
	MAX TA			20	20	2	2	2	2	2	2	2	
Common-mode input voltage range	25°C			0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	0 to V _{DD} -1	V
	Full range			0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	0 to V _{DD} -1.5	
I _{OH} High-level output current	V _{IP} = 1 V	25°C			0.1	0.1	0.1	0.1	0.1	0.1	0.1	0.1	mA
		Full range			1	1	1	1	1	1	1	1	
I _{OL} Low-level output current	V _{IP} = -1 V, V _{OL} = 1.5 V	25°C			150	400	150	400	150	400	150	400	mA
		Full range			700	700	700	700	700	700	700	700	
I _{DD} Supply current (four comparators)	V _{DD} = 1 V, No load	25°C			6	16	6	16	6	16	6	16	mA
		Full range			0.3	0.6	0.3	0.6	0.3	0.6	0.3	0.6	

† All characteristics are measured with zero common-mode input voltage unless otherwise noted. Full range is -55°C to 125°C for TLC354M, -40°C to 85°C for TLC354I, and 0°C to 70°C for TLC354C. IMPORTANT: See Parameter Measurement Information.
 NOTE 4: The offset voltage limits given are the maximum values required to drive the output above 4 V or below 400 mV with a 10-kΩ resistor between the output and V_{DD}. They can be verified by applying the limit value to the input and checking for the appropriate output state.

switching characteristics, VDD = 5 V, TA = 25°C

PARAMETER	TEST CONDITIONS			MIN	TYP	MAX	UNIT
	Response time	R _L connected to 5 V through 5.1 kΩ, C _L = 15 pF*, See Note 5	TTL-level input step				
Response time		100-mV input step with 5-mV overdrive	650				nS
		TTL-level input step	200				

* C_L includes probe and jig capacitance.
 NOTE 5: The response time specified is the interval between the input step function and the instant when the output crosses 1.4 V.



PARAMETER MEASUREMENT INFORMATION

The digital output stage of the TLC354 can be damaged if it is held in the linear region of the transfer curve. Conventional operational amplifier/comparator testing incorporates the use of a servo-loop that is designed to force the device output to a level within this linear region. Since the servo-loop method of testing cannot be used, the following alternative for measuring parameters such as input offset voltage, common-mode rejection, etc., are offered.

To verify that the input offset voltage falls within the limits specified, the limit value is applied to the input as shown in Figure 1(a). With the noninverting input positive with respect to the inverting input, the output should be high. With the input polarity reversed, the output should be low.

A similar test can be made to verify the input offset voltage at the common-mode extremes. The supply voltages can be slewed as shown in Figure 1(b) for the V_{ICR} test, rather than changing the input voltages, to provide greater accuracy.

A close approximation of the input offset voltage can be obtained by using a binary search method to vary the differential input voltage while monitoring the output state. When the applied input voltage differential is equal, but opposite in polarity, to the input offset voltage, the output will change states.

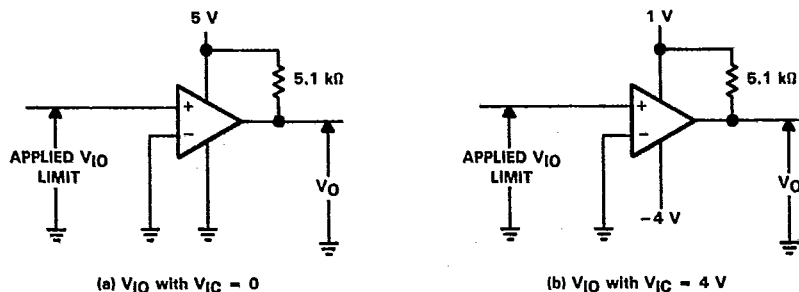


FIGURE 1. METHOD FOR VERIFYING THAT INPUT OFFSET VOLTAGE IS WITHIN SPECIFIED LIMITS

3 Voltage Comparators

TLC354M, TLC354I, TLC354C
LinCMOS™ QUADRUPLE DIFFERENTIAL COMPARATORS

T-73-53

PARAMETER MEASUREMENT INFORMATION

Figure 2 illustrates a practical circuit for direct dc measurement of input offset voltage that does not bias the comparator into the linear region. The circuit consists of a switching-mode servo loop in which U1a generates a triangular waveform of approximately 20-mV amplitude. U1b acts as a buffer, with C2 and R4 removing any residual dc offset. The signal is then applied to the inverting input of the comparator under test, while the noninverting input is driven by the output of the integrator formed by U1c through the voltage divider formed by R9 and R10. The loop reaches a stable operating point when the output of the comparator under test has a duty cycle of exactly 50%, which can only occur when the incoming triangle wave is "sliced" symmetrically or when the voltage at the noninverting input exactly equals the input offset voltage.

Voltage divider R9 and R10 provides a step-up of the input offset voltage by a factor of 100 to make measurement easier. The values of R5, R8, R9, and R10 can significantly influence the accuracy of the reading; therefore, it is suggested that their tolerance level be 1% or lower.

Measuring the extremely low values of input current requires isolation from all other sources of leakage current and compensation for the leakage of the test socket and board. With a good picoammeter, the socket and board leakage can be measured with no device in the socket. Subsequently, this open-socket leakage value can be subtracted from the measurement obtained with a device in the socket to obtain the actual input current of the device.

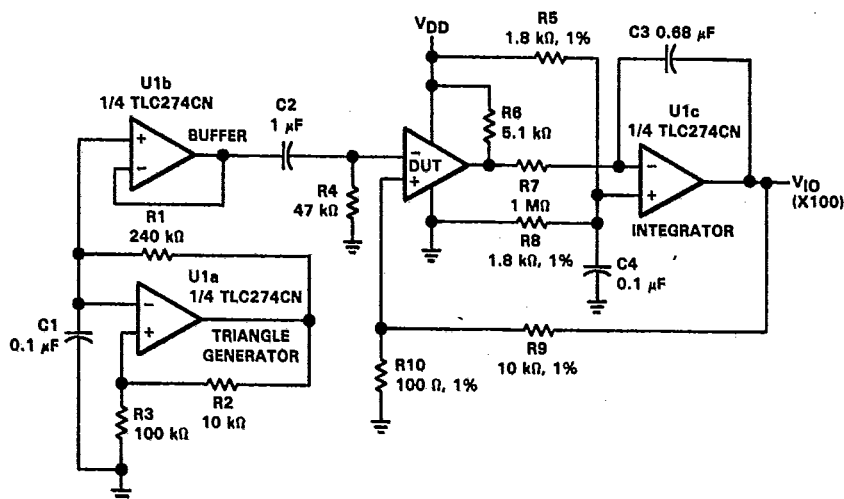


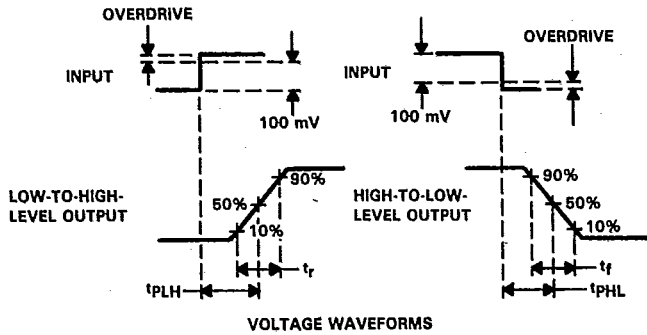
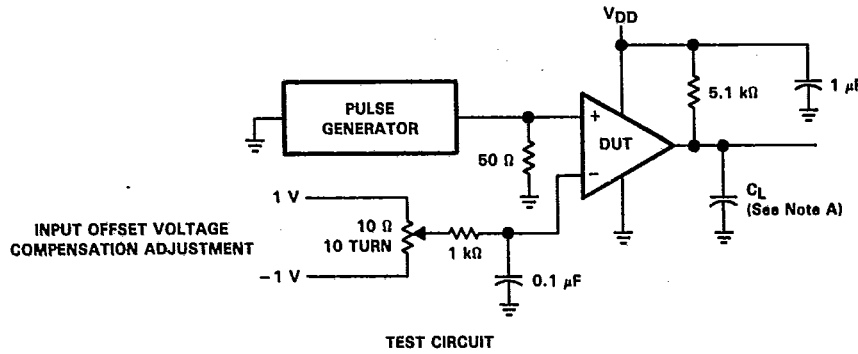
FIGURE 2. CIRCUIT FOR INPUT OFFSET VOLTAGE MEASUREMENT

3

Voltage Comparators

PARAMETER MEASUREMENT INFORMATION

Response time is defined as the interval between the application of an input step function and the instant when the output reaches 50% of its maximum value. Response time, low-to-high-level output, is measured from the leading edge of the input pulse, while response time, high-to-low-level output, is measured from the trailing edge of the input pulse. Response-time measurement at low input signal levels can be greatly affected by the input offset voltage. The offset voltage should be balanced by the adjustment at the inverting input (as shown in Figure 3) so that the circuit is just at the transition point. Then a low signal, for example 105-mV or 5-mV overdrive, will cause the output to change state.



NOTE A: C_L includes probe and jig capacitance.

FIGURE 3. RESPONSE, RISE, AND FALL TIMES CIRCUIT AND VOLTAGE WAVEFORMS